

Features

- EE Programmable 65,536 x 1-, 131,072 x 1-, 262,144 x 1-, 524,288 x 1-, 1,048,576 x 1-, 2,097,152 x 1-, and 4,194,304 x 1-bit Serial Memories Designed to Store Configuration Programs for Field Programmable Gate Arrays (FPGAs)
- Supports both 3.3V and 5.0V Operating Voltage Applications
- In-System Programmable (ISP) via Two-Wire Bus
- Simple Interface to SRAM FPGAs
- Compatible with Atmel AT6000, AT40K and AT94K Devices, Altera® FLEX®, APEX™ Devices, ORCA®, Xilinx® XC3000, XC4000, XC5200, Spartan®, Virtex® FPGAs
- Cascadable Read-back to Support Additional Configurations or Higher-density Arrays
- Very Low-power CMOS EEPROM Process
- Programmable Reset Polarity
- Available in 6 mm x 6 mm x 1 mm 8-lead LAP (Pin-compatible with 8-lead SOIC/VOIC Packages), 8-lead PDIP, 8-lead SOIC, 20-lead PLCC, 20-lead SOIC and 44-lead TQFP Packages
- Emulation of Atmel's AT24CXXX Serial EEPROMs
- Low-power Standby Mode
- High-reliability
 - Endurance: 100,000 Write Cycles
 - Data Retention: 90 Years for Industrial Parts (at 85° C) and 190 Years for Commercial Parts (at 70° C)
- Green (Pb/Halide-free/RoHS Compliant) Package Options Available

1. Description

The AT17LV series FPGA Configuration EEPROMs (Configurators) provide an easy-to-use, cost-effective configuration memory for Field Programmable Gate Arrays. The AT17LV series device is packaged in the 8-lead LAP, 8-lead PDIP, 8-lead SOIC, 20-lead PLCC, 20-lead SOIC and 44-lead TQFP, see [Table 1-1](#). The AT17LV series Configurators uses a simple serial-access procedure to configure one or more FPGA devices. The user can select the polarity of the reset function by programming four EEPROM bytes. These devices also support a write-protection mechanism within its programming mode.

The AT17LV series configurators can be programmed with industry-standard programmers, Atmel's ATDH2200E Programming Kit or Atmel's ATDH2225 ISP Cable.



FPGA Configuration EEPROM Memory

AT17LV65
AT17LV128
AT17LV256
AT17LV512
AT17LV010
AT17LV002
AT17LV040

**3.3V and 5V
System Support**



11. Absolute Maximum Ratings*

Operating Temperature	-40° C to +85° C
Storage Temperature	-65° C to +150° C
Voltage on Any Pin with Respect to Ground	-0.1V to $V_{CC} + 0.5V$
Supply Voltage (V_{CC})	-0.5V to +7.0V
Maximum Soldering Temp. (10 sec. @ 1/16 in.).....	260° C
ESD ($R_{ZAP} = 1.5K, C_{ZAP} = 100 \text{ pF}$).....	2000V

*NOTICE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those listed under operating conditions is not implied. Exposure to Absolute Maximum Rating conditions for extended periods of time may affect device reliability.

12. Operating Conditions

Symbol	Description		3.3V		5V		Units
			Min	Max	Min	Max	
V_{CC}	Commercial	Supply voltage relative to GND -0° C to +70° C	3.0	3.6	4.75	5.25	V
	Industrial	Supply voltage relative to GND -40° C to +85° C	3.0	3.6	4.5	5.5	V

13. DC Characteristics

$V_{CC} = 3.3V \pm 10\%$

Symbol	Description	AT17LV65/ AT17LV128/ AT17LV256		AT17LV512/ AT17LV010		AT17LV002/ AT17LV040		Units
		Min	Max	Min	Max	Min	Max	
V_{IH}	High-level Input Voltage	2.0	V_{CC}	2.0	V_{CC}	2.0	V_{CC}	V
V_{IL}	Low-level Input Voltage	0	0.8	0	0.8	0	0.8	V
V_{OH}	High-level Output Voltage ($I_{OH} = -2.5$ mA)	2.4		2.4		2.4		V
V_{OL}	Low-level Output Voltage ($I_{OL} = +3$ mA)							
V_{OH}	High-level Output Voltage ($I_{OH} = -2$ mA)	2.4		2.4		2.4		V
V_{OL}	Low-level Output Voltage ($I_{OL} = +3$ mA)							
I_{CCA}	Supply Current, Active Mode		5		5		5	mA
I_L	Input or Output Leakage Current ($V_{IN} = V_{CC}$ or GND)	-10	10	-10	10	-10	10	μ A
I_{CCS}	Supply Current, Standby Mode	Commercial	50		100		150	μ A
		Industrial	100		100		150	μ A

14. DC Characteristics

$V_{CC} = 5V \pm 5\%$ Commercial; $V_{CC} = 5V \pm 10\%$ Industrial

Symbol	Description	AT17LV65/ AT17LV128/ AT17LV256		AT17LV512/ AT17LV010		AT17LV002/ AT17LV040		Units
		Min	Max	Min	Max	Min	Max	
V_{IH}	High-level Input Voltage	2.0	V_{CC}	2.0	V_{CC}	2.0	V_{CC}	V
V_{IL}	Low-level Input Voltage	0	0.8	0	0.8	0	0.8	V
V_{OH}	High-level Output Voltage ($I_{OH} = -2.5$ mA)	3.7		3.86		3.86		V
V_{OL}	Low-level Output Voltage ($I_{OL} = +3$ mA)							
V_{OH}	High-level Output Voltage ($I_{OH} = -2$ mA)	3.6		3.76		3.76		V
V_{OL}	Low-level Output Voltage ($I_{OL} = +3$ mA)							
I_{CCA}	Supply Current, Active Mode		10		10		10	mA
I_L	Input or Output Leakage Current ($V_{IN} = V_{CC}$ or GND)	-10	10	-10	10	-10	10	μ A
I_{CCS}	Supply Current, Standby Mode	Commercial	75		200		350	μ A
		Industrial	150		200		350	μ A

17. AC Characteristics

$V_{CC} = 3.3V \pm 10\%$

Symbol	Description	AT17LV65/128/256				AT17LV512/010/002/040				Units
		Commercial		Industrial		Commercial		Industrial		
		Min	Max	Min	Max	Min	Max	Min	Max	
$T_{OE}^{(1)}$	OE to Data Delay		50		55		50		55	ns
$T_{CE}^{(1)}$	\overline{CE} to Data Delay		60		60		55		60	ns
$T_{CAC}^{(1)}$	CLK to Data Delay		75		80		55		60	ns
T_{OH}	Data Hold from \overline{CE} , OE, or CLK	0		0		0		0		ns
$T_{DF}^{(2)}$	\overline{CE} or OE to Data Float Delay		55		55		50		50	ns
T_{LC}	CLK Low Time	25		25		25		25		ns
T_{HC}	CLK High Time	25		25		25		25		ns
T_{SCE}	\overline{CE} Setup Time to CLK (to guarantee proper counting)	35		60		30		35		ns
T_{HCE}	\overline{CE} Hold Time from CLK (to guarantee proper counting)	0		0		0		0		ns
T_{HOE}	OE High Time (guarantees counter is reset)	25		25		25		25		ns
F_{MAX}	Maximum Clock Frequency		10		10		15		10	MHz

- Notes: 1. AC test lead = 50 pF.
 2. Float delays are measured with 5 pF AC loads. Transition is measured ± 200 mV from steady-state active levels.

18. AC Characteristics when Cascading

$V_{CC} = 3.3V \pm 10\%$

Symbol	Description	AT17LV65/128/256				AT17LV512/010/002/040				Units
		Commercial		Industrial		Commercial		Industrial		
		Min	Max	Min	Max	Min	Max	Min	Max	
$T_{CDF}^{(2)}$	CLK to Data Float Delay		60		60		50		50	ns
$T_{OCK}^{(1)}$	CLK to \overline{CEO} Delay		55		60		50		55	ns
$T_{OCE}^{(1)}$	\overline{CE} to \overline{CEO} Delay		55		60		35		40	ns
$T_{OOE}^{(1)}$	\overline{RESET}/OE to \overline{CEO} Delay		40		45		35		35	ns
F_{MAX}	Maximum Clock Frequency		8		8		12.5		10	MHz

- Notes: 1. AC test lead = 50 pF.
 2. Float delays are measured with 5 pF AC loads. Transition is measured ± 200 mV from steady-state active levels.

19. AC Characteristics

$V_{CC} = 5V \pm 5\%$ Commercial; $V_{CC} = 5V \pm 10\%$ Industrial

Symbol	Description	AT17LV65/128/256				AT17LV512/010/002/040				Units
		Commercial		Industrial		Commercial		Industrial		
		Min	Max	Min	Max	Min	Max	Min	Max	
$T_{OE}^{(1)}$	OE to Data Delay		30		35		30		35	ns
$T_{CE}^{(1)}$	\overline{CE} to Data Delay		45		45		45		45	ns
$T_{CAC}^{(1)}$	CLK to Data Delay		50		55		50		50	ns
T_{OH}	Data Hold from \overline{CE} , OE, or CLK	0		0		0		0		ns
$T_{DF}^{(2)}$	\overline{CE} or OE to Data Float Delay		50		50		50		50	ns
T_{LC}	CLK Low Time	20		20		20		20		ns
T_{HC}	CLK High Time	20		20		20		20		ns
T_{SCE}	\overline{CE} Setup Time to CLK (to guarantee proper counting)	35		40		20		25		ns
T_{HCE}	\overline{CE} Hold Time from CLK (to guarantee proper counting)	0		0		0		0		ns
T_{HOE}	OE High Time (guarantees counter is reset)	20		20		20		20		ns
F_{MAX}	Maximum Clock Frequency		12.5		12.5		15		15	MHz

- Notes: 1. AC test lead = 50 pF.
 2. Float delays are measured with 5 pF AC loads. Transition is measured ± 200 mV from steady-state active levels.

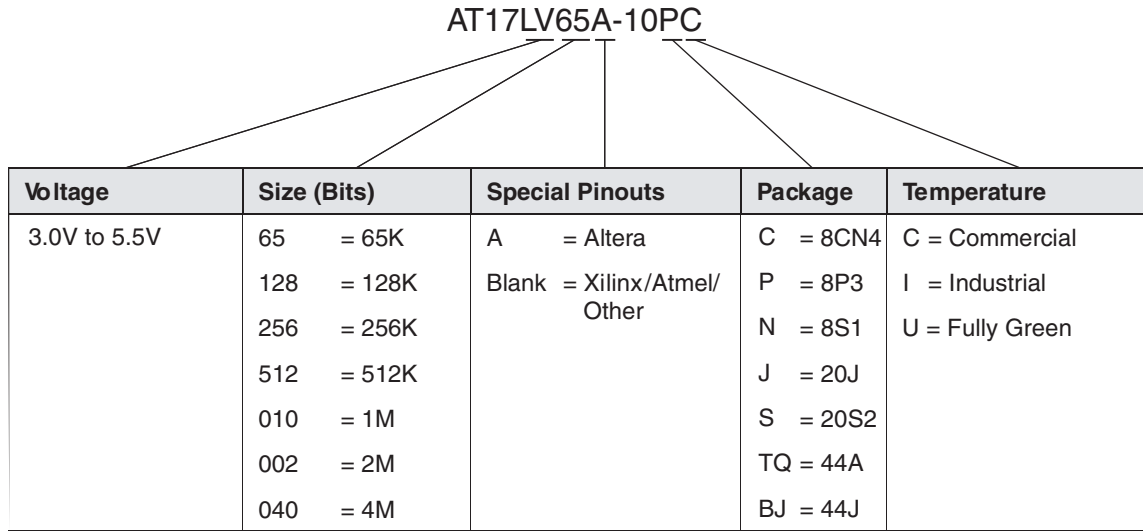
20. AC Characteristics when Cascading

$V_{CC} = 5V \pm 5\%$ Commercial; $V_{CC} = 5V \pm 10\%$ Industrial

Symbol	Description	AT17LV65/128/256				AT17LV512/010/002/040				Units
		Commercial		Industrial		Commercial		Industrial		
		Min	Max	Min	Max	Min	Max	Min	Max	
$T_{CDF}^{(2)}$	CLK to Data Float Delay		50		50		50		50	ns
$T_{OCK}^{(1)}$	CLK to \overline{CEO} Delay		35		40		35		40	ns
$T_{OCE}^{(1)}$	\overline{CE} to \overline{CEO} Delay		35		35		35		35	ns
$T_{OOE}^{(1)}$	\overline{RESET}/OE to \overline{CEO} Delay		30		35		30		30	ns
F_{MAX}	Maximum Clock Frequency		10		10		12.5		12.5	MHz

- Notes: 1. AC test lead = 50 pF.
 2. Float delays are measured with 5 pF AC loads. Transition is measured ± 200 mV from steady-state active levels.

Figure 21-1. Ordering Code



Package Type	
8CN4	8-lead, 6 mm x 6 mm x 1 mm, Leadless Array Package (LAP) – Pin-compatible with 8-lead SOIC/VOID Packages
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)
20J	20-lead, Plastic J-leaded Chip Carrier (PLCC)
20S2	20-lead, 0.300" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)
44A	44-lead, Thin (1.0 mm) Plastic Quad Flat Package Carrier (TQFP)

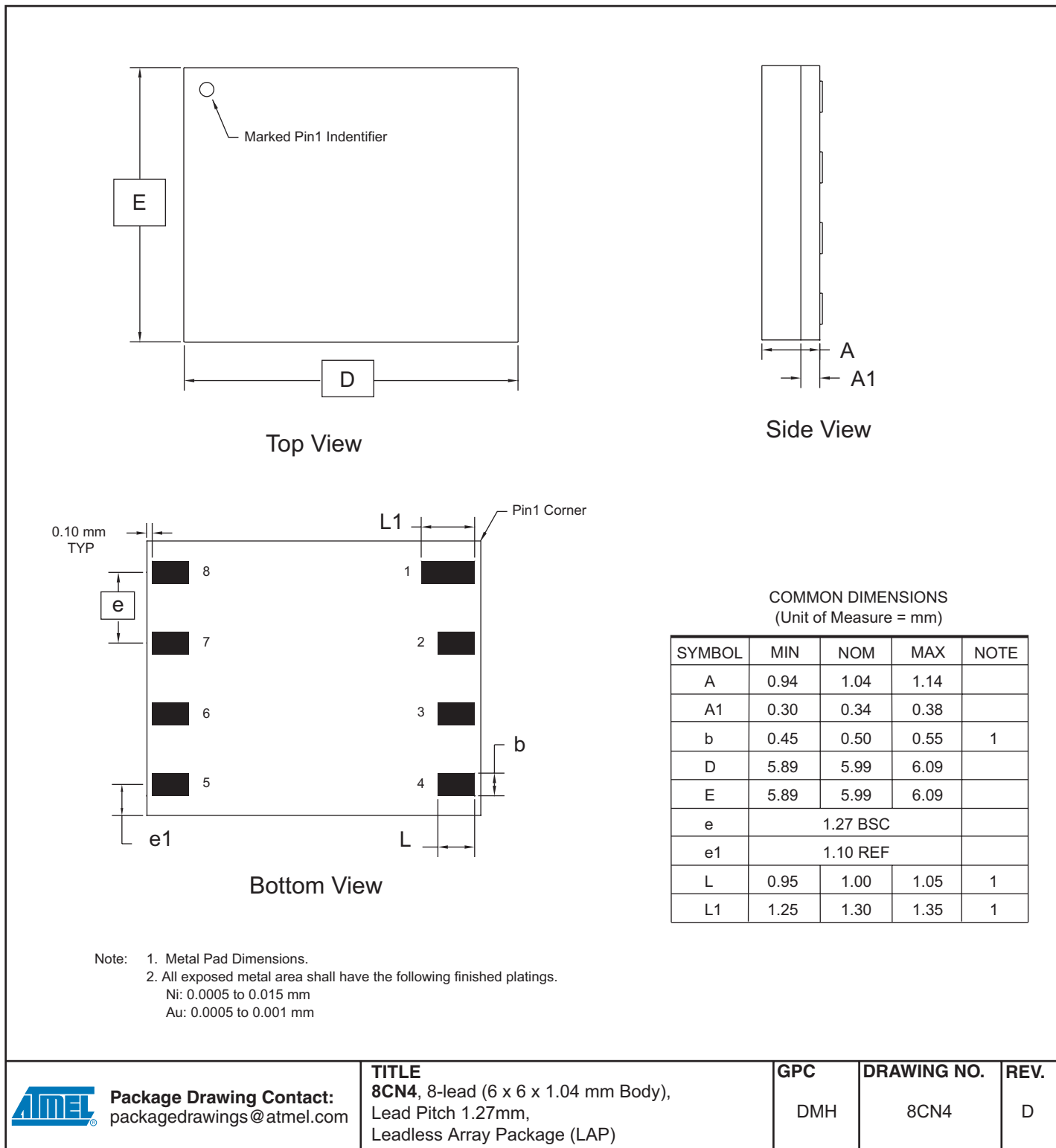
22.2 Green Package Options (Pb/Halide-free/RoHS Compliant)

Memory Size	Ordering Code	Package	Operation Range
256-Kbit ⁽¹⁾	AT17LV256-10CU	8CN4	Industrial (-40° C to 85° C)
	AT17LV256-10JU	20J	
	AT17LV256-10NU	8S1	
	AT17LV256-10PU	8P3	
	AT17LV256-10SU	20S2	
512-Kbit ⁽¹⁾	AT17LV512-10CU	8CN4	
	AT17LV512-10JU	20J	
1-Mbit ⁽¹⁾	AT17LV010-10CU	8CN4	
	AT17LV010-10JU	20J	
	AT17LV010-10PU	8P3	
2-Mbit ⁽¹⁾	AT17LV002-10CU	8CN4	
	AT17LV002-10JU	20J	
	AT17LV002-10SU	20S2	
	AT17LV002-10TQU	44A	
4-Mbit ⁽¹⁾	AT17LV040-10TQU	44A	

Note: 1. For operating 5V operating voltage, please refer to the corresponding AC and DC Characteristics.

23. Packaging Information

23.1 8CN4 – LAP



Package Drawing Contact:
packagedrawings@atmel.com

TITLE
8CN4, 8-lead (6 x 6 x 1.04 mm Body),
Lead Pitch 1.27mm,
Leadless Array Package (LAP)

GPC
DMH

DRAWING NO.
8CN4

REV.
D